Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic
Overall Length:
Between 0.264 inches and 0.274 inches
Overall Diameter:
0.125 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.125 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, dc
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Power Rating Per Characteristic:
25.0 watts small-signal input power, common-collector minor
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Thread Series Designator:
Unc
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0